

G.Skill Intros "Extreme Performance" DDR4 RAM

Written by Marco Attard
14 September 2017



G.Skill announces the DDR4-4600MHz CL19-- a DDR4 memory kit promising "extreme performance" built using hand-selected Samsung B-die IC components and aluminium heatspreaders in either black or white.

Designed for dual-channel operation on the Intel X299 HEDT platform, the kit offers total capacity of 16GB (8GB X2), and promises the kind of speed that "was only achievable under extreme overclocking with liquid nitrogen cooling."

It is certified to run at DDR4-4600MHz CL 19-23-23-43 at 1.5V, at least validated in use with an Intel Kaby Lake-X Core i7-7740X processor installed on the ASRock X299 OC Formula motherboard.

The DDR4-4600MHz CL19 hits the market by end September 2017.

Go [G.SKILL Announces New DDR4-4600MHz Extreme Performance Trident Z Memory Kit](#)